



ARPES-parameterized Hubbard approach to d -wave superconductors

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In the last decade, the Angle Resolved Photoemission Spectroscopy (ARPES) has achieved important advances in both energy and angular resolutions, which provide a direct measurement of the single-particle dispersion relation and superconducting gap. These dispersion relation data permit a full determination of the self-energy, first and second neighbor parameters in the Hubbard model. This model and its generalizations offer a simple and general way to describe the electronic correlation in solids. In particular, the parameters of correlated hopping interactions, responsible of the d -wave superconductivity in the generalized Hubbard model, are determined from ARPES data within the mean-field approximation. In this work, we study the doping effects on the critical temperature (T_c), d -wave superconducting gap (Δ), and electronic specific heat of cuprate superconductors, such as $\text{La}_{2-x}\text{Sr}_x\text{CuO}_4$ and $\text{Bi}_2\text{Sr}_{2-x}\text{La}_x\text{CuO}_{6+\delta}$, by solving numerically two coupled integral equations for determining the chemical potential and the superconducting gap or T_c . Finally, the calculated electronic specific heat is compared with experimental results.

The Model

We use a Hubbard model where first- (Δ_1) and second-neighbor (Δ_2) correlated-hoppings are considered in addition to the on-site (U) Coulombic interaction, which can be written as [1]

$$\hat{H} = \epsilon_0 \sum_{i,\sigma} \hat{c}_{i,\sigma}^\dagger \hat{c}_{i,\sigma} + t \sum_{\langle i,j \rangle} \hat{c}_{i,\sigma}^\dagger \hat{c}_{j,\sigma} + t' \sum_{\langle\langle i,j \rangle\rangle} \hat{c}_{i,\sigma}^\dagger \hat{c}_{j,\sigma} + U \sum_i \hat{n}_{i,\uparrow} \hat{n}_{i,\downarrow} + \Delta_1 \sum_{\langle i,j \rangle} \hat{c}_{i,\sigma}^\dagger \hat{c}_{j,\sigma} (\hat{n}_{i-\sigma} + \hat{n}_{j-\sigma}) + \Delta_2 \sum_{\langle\langle i,j \rangle\rangle} \hat{c}_{i,\sigma}^\dagger \hat{c}_{j,\sigma} \hat{n}_i$$

Mean-field dispersion relation

$$\epsilon_{MF}(\mathbf{k}) = \epsilon_{eff} + 2t_{eff} [\cos(k_x a) + \cos(k_y a)] + 4t'_{eff} \cos(k_x a) \cos(k_y a)$$

Mean-field parameters

Self energy: $\epsilon_{eff} = \epsilon_0 + nU/2$ First neighbor hopping parameter: $t_{eff} = t + n\Delta t$ Second neighbor hopping parameter: $t'_{eff} = t' + 2n\Delta t_2$

BCS Coupled Equations

For singlet Cooper pairs, the BCS coupled equations are given by

$$\begin{cases} \Delta(\mathbf{k}) = -\frac{1}{2N_s} \sum_{\mathbf{k}'} V_{\mathbf{k}\mathbf{k}'} \Delta(\mathbf{k}') \tanh\left(\frac{E(\mathbf{k}')}{2k_B T}\right) \\ n-1 = -\frac{1}{N_s} \sum_{\mathbf{k}'} \frac{\epsilon(\mathbf{k}') - \mu}{E(\mathbf{k}')} \tanh\left(\frac{E(\mathbf{k}')}{2k_B T}\right) \end{cases}$$

where $E(\mathbf{k}) = \sqrt{(\epsilon_{MF}(\mathbf{k}) - \mu)^2 + \Delta^2(\mathbf{k})}$ and $V_{\mathbf{k}\mathbf{k}+\mathbf{q}} = U + 2\Delta t_1 \gamma(\mathbf{k}+\mathbf{q}, \mathbf{k}'+\mathbf{q}) + \Delta t_2 [\beta(\mathbf{k}+\mathbf{q}) + \beta(-\mathbf{k}+\mathbf{q}) + \beta(\mathbf{k}'+\mathbf{q}) + \beta(-\mathbf{k}'+\mathbf{q})]$
with $\beta(\mathbf{k}) = 2[\cos(k_x a) + \cos(k_y a)]$, and $\gamma(\mathbf{k}, \mathbf{k}') = 4 \cos(k_x a) \cos(k_y a) + 4 \cos(k'_x a) \cos(k'_y a)$

For a d -wave superconducting gap, the BCS coupled equations are given by

$$\begin{cases} 1 = \frac{4\Delta t_1}{2N_s} \sum_{\mathbf{k}'} \frac{[\cos(k_x a) - \cos(k_y a)]}{E(\mathbf{k}')} \tanh\left(\frac{E(\mathbf{k}')}{2k_B T}\right) \\ n-1 = -\frac{1}{N_s} \sum_{\mathbf{k}'} \frac{\epsilon(\mathbf{k}') - \mu}{E(\mathbf{k}')} \tanh\left(\frac{E(\mathbf{k}')}{2k_B T}\right) \end{cases}$$

where $E(\mathbf{k}) = \sqrt{(\epsilon_{MF}(\mathbf{k}) - \mu)^2 + \Delta^2(\mathbf{k})}$ with $\Delta(\mathbf{k}) = \Delta [\cos(k_x a) - \cos(k_y a)]$.

Electronic specific heat

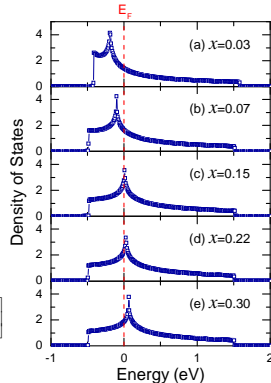
$$C_{el} = \frac{2k_B \beta^2 a^2}{4\pi^2} \int_{IBZ} f[E(\mathbf{k})] \{1 - f[E(\mathbf{k})]\} \left[E^2(\mathbf{k}) + \beta E(\mathbf{k}) \frac{dE(\mathbf{k})}{d\beta} \right] dk_x dk_y$$

where $\beta = 1/k_B T$ and $f(E)$ is the Fermi-Dirac distribution.

Density of States

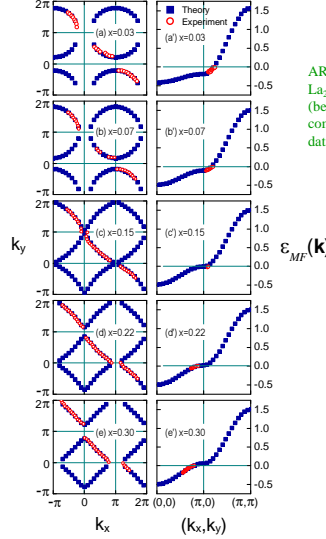
Electronic density of states (DOS) for $\text{La}_{2-x}\text{Sr}_x\text{CuO}_4$. Notice that for $x=0.15$, the Fermi level (E_F) coincides with the van Hove singularity and then, the critical temperature is a maximum, as expected. By integrating $DOS(E)$ up to E_F we obtain the electronic density (n).

$$DOS(E) = -\frac{1}{\pi} \lim_{\eta \rightarrow 0^+} \text{Im} \left[\sum_{\mathbf{k}} \frac{1}{E - \epsilon_{MF}(\mathbf{k}) + i\eta} \right]$$



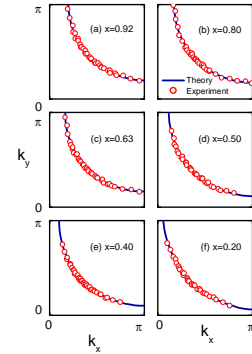
References

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ARPES Data

ARPES data (red open circles) obtained from $\text{La}_{2-x}\text{Sr}_x\text{CuO}_4$ [2] (left figure) and $\text{Bi}_2\text{Sr}_{2-x}\text{La}_x\text{CuO}_{6+\delta}$ (below figure) [3] with different doping levels in comparison with the calculated dispersion relation (blue data).



Model parameters determined from ARPES data

$\text{La}_{2-x}\text{Sr}_x\text{CuO}_4$

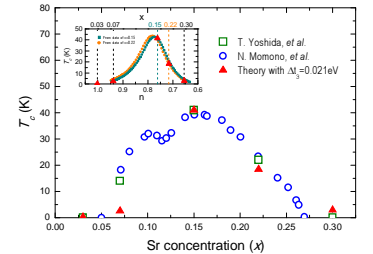
x	Tc [K]	t_{eff} [eV]	t'_{eff} [eV]	ϵ_{eff} [eV]	n	Δ_{eff} [eV]
0.03	0	-0.25	0.097	0.199	1.002	0.021
0.07	14	-0.25	0.077	0.209	0.938	0.021
0.15	41	-0.25	0.064	0.260	0.761	0.021
0.22	22	-0.25	0.060	0.268	0.716	0.021
0.30	0	-0.25	0.056	0.290	0.655	0.021

$\text{Bi}_2\text{Sr}_{2-x}\text{La}_x\text{CuO}_{6+\delta}$

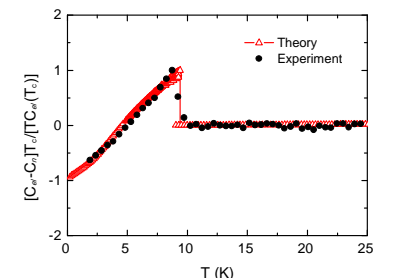
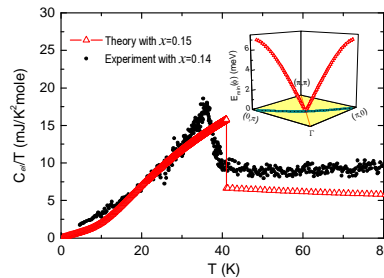
x	Tc [K]	t_{eff} [eV]	t'_{eff} [eV]	ϵ_{eff} [eV]	n	Δ_{eff} [eV]
0.80	0	-0.25	0.095	0.252	0.916	0
0.63	14	-0.25	0.098	0.276	0.884	0.0267
0.50	24	-0.25	0.097	0.329	0.776	-0.0234
0.40	34	-0.25	0.103	0.368	0.656	-0.0227
0.20	25	-0.25	0.098	0.377	0.655	-0.0173

$\text{La}_{2-x}\text{Sr}_x\text{CuO}_4$ Critical Temperature

Theoretical (solid triangles) critical temperature (T_c) as a function of the Sr concentration (x) in comparison with experimental data of T. Yoshida *et al.* (open squares) [2] and N. Momono *et al.* (open circles) [4]. Inset: T_c versus electronic density (n) for the Hamiltonian parameters obtained from $x=0.15$ (solid squares) and $x=0.22$ (solid circles) with the values of x indicated by dashed lines.



Electronic Specific Heat



Theoretical (open triangles) electronic specific heat (C_{el}) versus temperature (T) for $\text{La}_{2-x}\text{Sr}_x\text{CuO}_4$ with $x=0.15$ in comparison with the experimental one (solid circles) for $x=0.14$ [5]. Inset: Single excitation energy gap (open triangles) in the first Brillouin zone.

Theoretical (open triangles) normalized electronic specific heat (C_{el}/T) versus temperature (T) for $\text{Bi}_{1.7}\text{Sr}_{1.3}\text{Pb}_{0.3}\text{CuO}_{6+\delta}$ in comparison with the experimental one (solid circles) [6].